

2SA1738

Silicon PNP epitaxial planer type

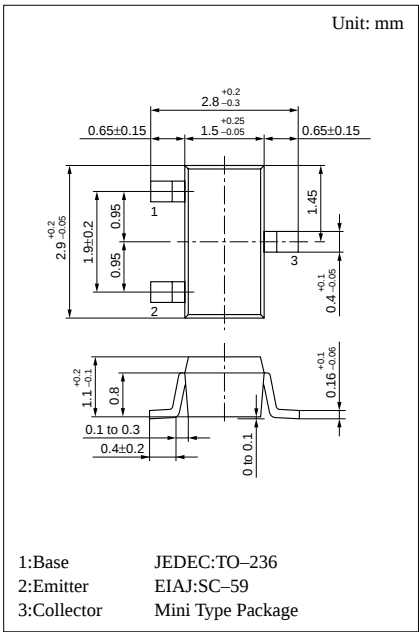
For high speed switching

Features

- High-speed switch (pair with 2SC3757)
- Low collector to emitter saturation voltage $V_{CE(sat)}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-15	V
Collector to emitter voltage	V_{CEO}	-15	V
Emitter to base voltage	V_{EBO}	-4	V
Peak collector current	I_{CP}	-100	mA
Collector current	I_C	-50	mA
Collector power dissipation	P_C	200	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 ~ +150	°C



Marking symbol : AK

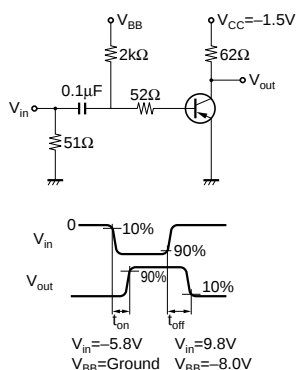
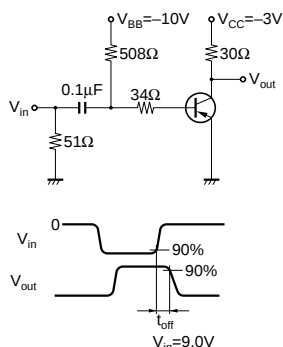
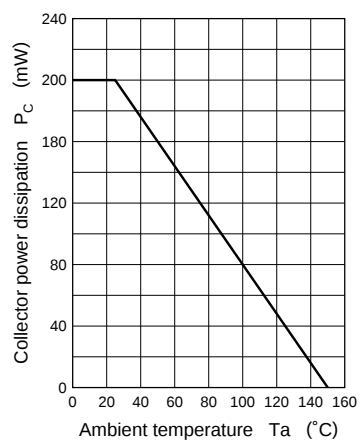
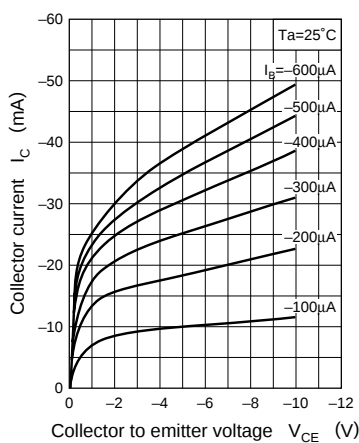
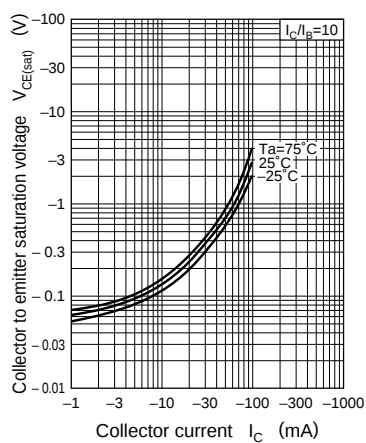
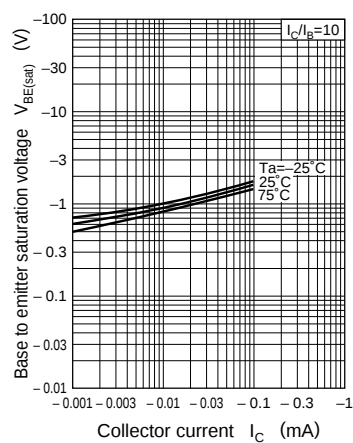
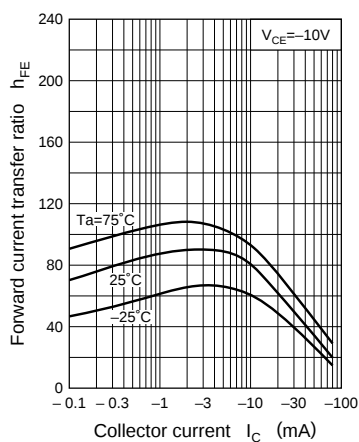
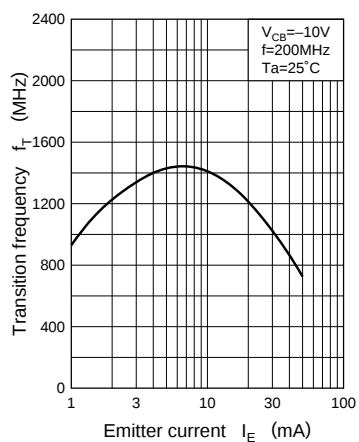
Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -8V, I_E = 0$			- 0.1	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -3V, I_C = 0$			- 0.1	μA
Forward current transfer ratio	h_{FE1}^*	$V_{CE} = -1V, I_C = -10mA$	50		150	
	h_{FE2}	$V_{CE} = -1V, I_C = -1mA$	30			
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10mA, I_B = -1mA$		- 0.1	- 0.2	V
Transition frequency	f_T	$V_{CB} = -10V, I_E = 10mA, f = 200MHz$	800	1500		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -5V, I_E = 0, f = 1MHz$		1		pF
Turn-on time	t_{on}	(Note 1) Next page		12		ns
Turn-off time	t_{off}	(Note 1) Next page		20		ns
Storage time	t_{stg}	(Note 1) Next page		19		ns

* h_{FE1} Rank classification

Rank	Q	R
h_{FE1}	50 ~ 120	90 ~ 150

Switching time measurement circuit

 t_{on}, t_{off} Test Circuit t_{stg} Test Circuit $P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $C_{ob} - V_{CB}$ 